

**Product data sheet** 

### **1. General description**

Planar passivated Silicon Controlled Rectifier (SCR) in a TO263 (D2PAK) surface mountable plastic package intended for use in applications requiring very high inrush current capability, high thermal cycling performance and high junction temperature capability ( $T_{i(max)}$  = 150 °C).

### 2. Features and benefits

- High bidirectional blocking voltage capability
- High junction operating temperature capability
- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- Surface mountable package
- Very high current surge capability

### 3. Applications

- Capacitive Discharge Ignition (CDI)
- Crowbar protection
- Inrush protection
- Motor control
- Voltage regulation

### 4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
$V_{RRM}$	repetitive peak reverse voltage		800			V	
I <sub>T(AV)</sub>	average on-state current	half sine wave;T <sub>mb</sub> ≤ 129 °C; <u>Fig 1</u>	12.7			A	
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave;T <sub>mb</sub> ≤ 129 °C; <u>Fig 2; Fig 3</u>	20			А	
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; Fig 4; Fig 5	210		A		
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		23	31		А
Tj	junction temperature			1	50		°C
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static cha	racteristics						
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1\text{A}; \text{ T}_{j} = 25 \text{ °C};$ Fig 7		-	4.5	32	mA
Dynamic c	haracteristics						

SCR

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 150 °C; exponential waveform; gate open circuit	1000	-	-	V/µs
		$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	500	-	-	V/µs

# 5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	А	anode		А — Дан К G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

# 6. Ordering information

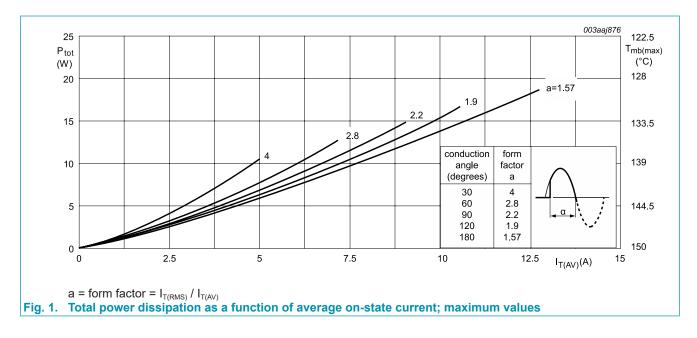
Table 3. Ordering information						
Type number	Package	Orderable part number	Packing	Small packing	Package	Package
	Name		method	quantity	version	issue date
TYN20B-800T	TO263	TYN20B-800TJ	Reel	800	TO263E	26-May-2017

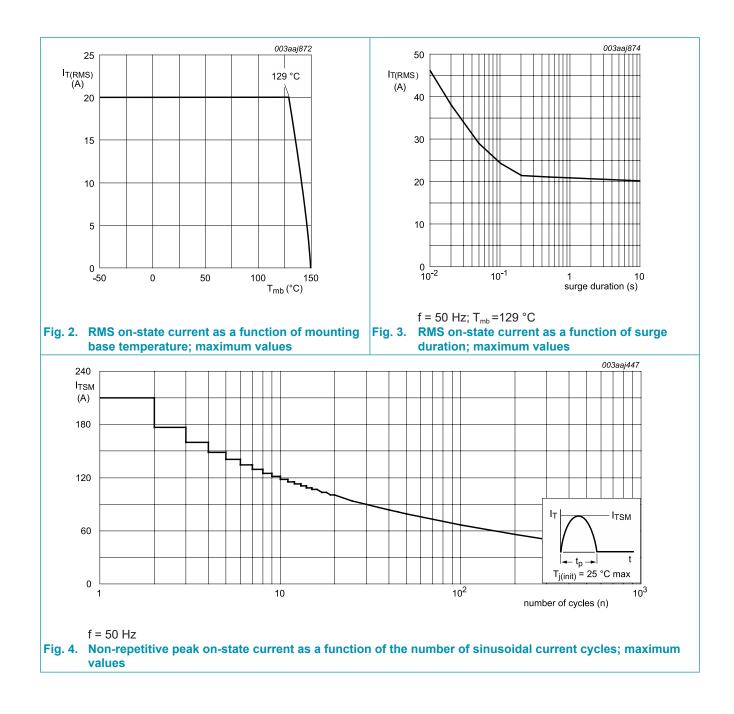
# 7. Limiting values

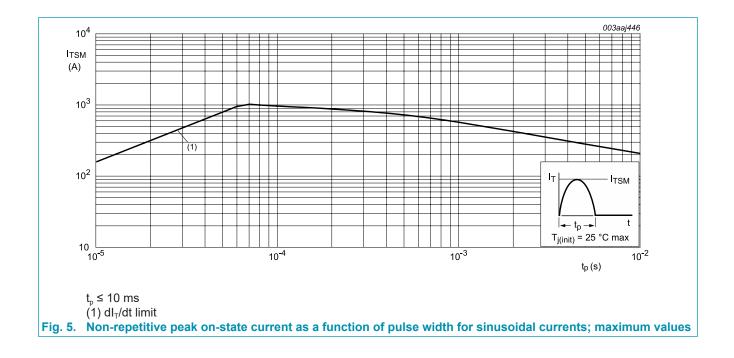
#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		800	V
V <sub>RRM</sub>	repetitive peak reverse voltage		800	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>mb</sub> ≤ 129 °C; <u>Fig 1</u>	12.7	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 129 °C; <u>Fig 2</u> ; <u>Fig 3</u>	20	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$ ; Fig 4; Fig 5	210	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	231	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	220.5	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>g</sub> = 70 mA	100	A/µs
I <sub>GM</sub>	peak gate current		5	А
$V_{\text{RGM}}$	peak reverse gate voltage		5	V
P <sub>GM</sub>	peak gate power		20	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	1	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>i</sub>	junction temperature		150	°C

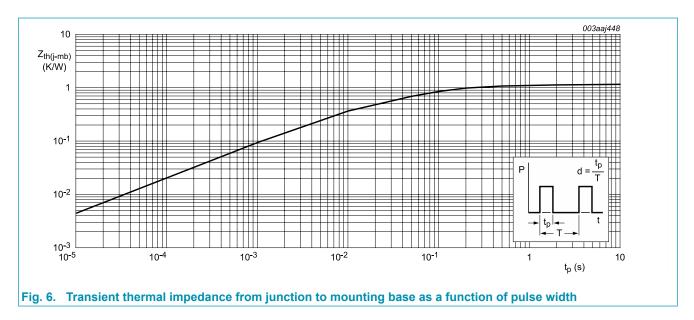






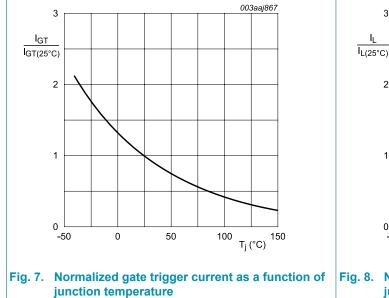
## 8. Thermal characteristics

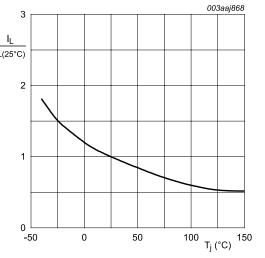
Table 5. Ther	mal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 6</u>	-	-	1.1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	minimum footprint, FR4 board	-	55	-	K/W



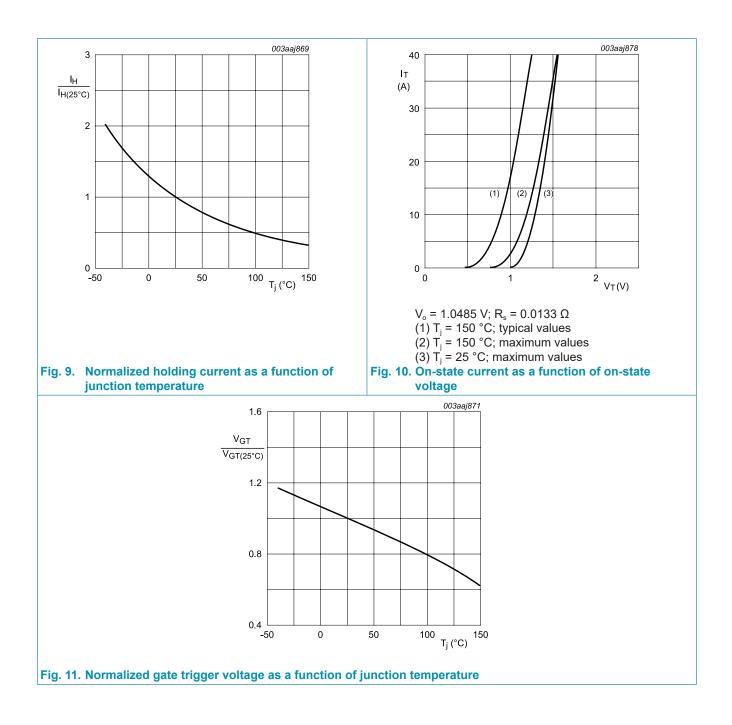
## 9. Characteristics

Table 6. Cl	naracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	4.5	32	mA
I <sub>L</sub>	latching current	$V_{\rm D}$ = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 8</u>	-	21	60	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V;T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	16	40	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 32 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 0.1 A;T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	0.7	1.3	V
		V <sub>D</sub> = 400V; I <sub>T</sub> = 0.1 A;T <sub>j</sub> =150 °C	0.2	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C	-	0.2	1	mA
I <sub>R</sub>	reverse current	V <sub>R</sub> = 800 V; T <sub>j</sub> = 150 °C	-	0.2	1	mA
Dynamic	characteristics					
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 150 °C; exponential waveform; gate open circuit	1000	-	-	V/µs
		$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; ( $V_{DM}$ = 67% of $V_{DRM}$ ); exponential waveform; gate open circuit	500	-	-	V/µs

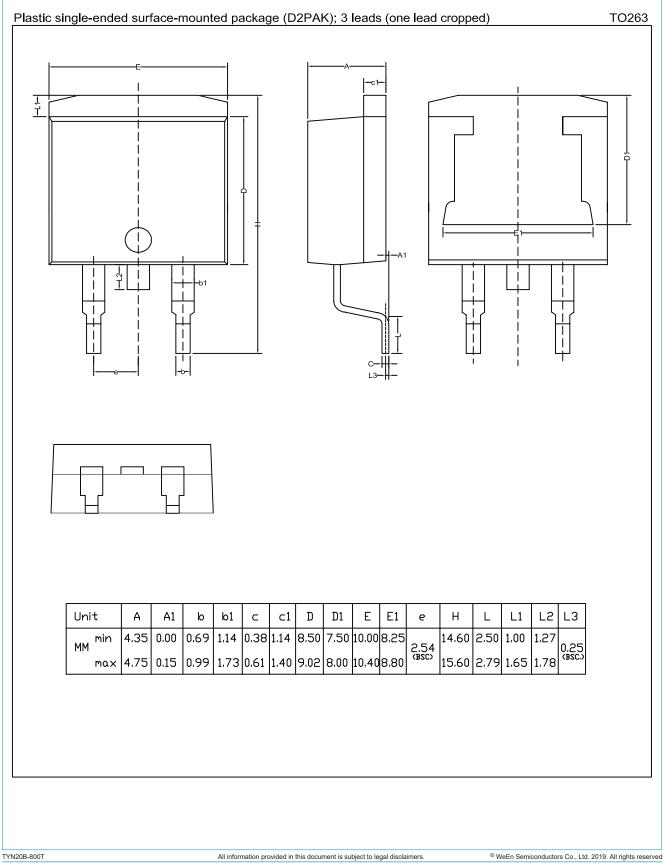








# 10. Package outline



# 11. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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